TOSHIBA Transistor Silicon NPN Triple Diffused Type

2SC5354

High-Speed and High-Voltage Switching Applications Switching Regulator Applications High-Speed DC-DC Converter Applications

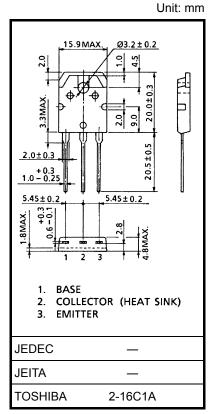
• Excellent switching times: $t_r = 0.7 \mu s \text{ (max)}$

 $t_f = 0.5 \mu s \text{ (max) (IC} = 2 \text{ A)}$

• High breakdown voltage: $V_{CEO} = 800 \text{ V}$

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	900	V	
Collector-emitter voltage		V _{CEO}	800	V	
Emitter-base voltage		V _{EBO}	7	٧	
Collector current	DC	IC	5	А	
	Pulse	I _{CP}	8		
Base current		ΙB	2	Α	
Collector power dissipation		P _C	100	۱۸/	
(Tc = 25°C)			100	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 4.7 g (typ.)

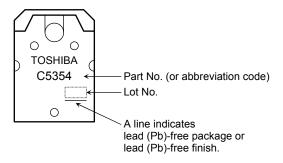
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Tc = 25°C)

Chara	Characteristics Symbol Test Condition		Min	Тур.	Max	Unit		
Collector cut-off current		I _{CBO}	V _{CB} = 800 V, I _E = 0	_	_	100	μΑ	
Emitter cut-off current		I _{EBO}	V _{EB} = 7 V, I _C = 0	_	_	1	mA	
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _E = 0	900	_	_	V	
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	800	_	_	V	
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA	10	_	_		
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.5 A	15 —		_		
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = 2 A, I _B = 0.4 A	_	_	1.0	V	
Base-emitter saturation voltage		V _{BE} (sat)	I _C = 2 A, I _B = 0.4 A	_	_	1.3	V	
Switching time Sto	Rise time	t _r	$V_{CC} \approx -360 \text{ V}$ 20 µs $I_C = 2 \text{ A}$ 10 P $10 $	_	_	0.7		
	Storage time	t _{stg}		ı	_	4.0	μs	
	Fall time	t _f		1	_	0.5		

Marking



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